

**50V NPN LOW SATURATION TRANSISTOR**

**Features and Benefits**

- $BV_{CEO} > 50V$
- $I_C = 4A$  Continuous Collector Current
- Low Saturation Voltage (100mV max @ 1A)
- $R_{SAT} = 68 m\Omega$  for a low equivalent On-Resistance
- $h_{FE}$  specified up to 6A for high current gain hold up
- Low profile 0.6mm high package for thin applications
- $R_{\theta JA}$  efficient, 60% lower than SOT23
- 4mm<sup>2</sup> footprint, 50% smaller than SOT23
- **Lead-Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free. "Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

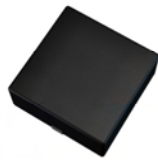
**Mechanical Data**

- Case: DFN2020B-3
- Case Material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal Package Height: 0.6mm
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.01 grams (approximate)

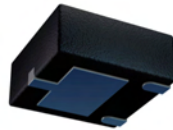
**Applications**

- MOSFET Gate Driving
- DC-DC Converters
- Charging circuits
- Motor Control
- Power switches

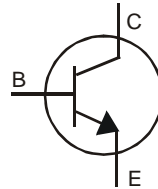
DFN2020B-3



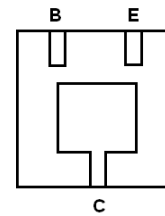
Top View



Bottom View



Device Symbol



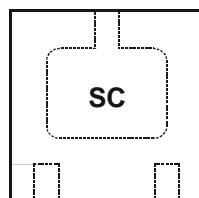
Bottom View  
Pin-Out

**Ordering Information**

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN619MATA	SC	7	8	3000

- Notes: 1. No purposefully added lead.  
2. Diodes Inc's "Green" policy can be found on our website at <http://www.diodes.com>

**Marking Information**



Top View

SC = Product Type Marking code

**Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

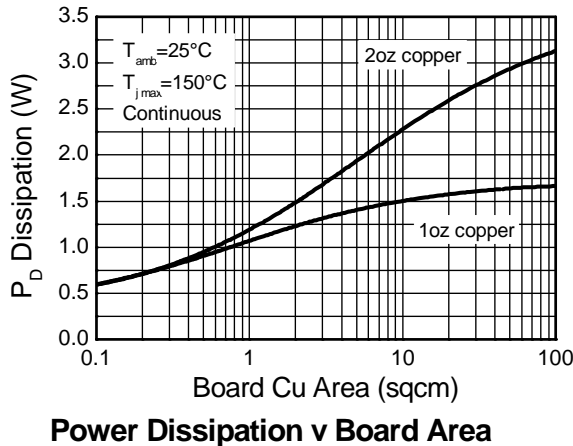
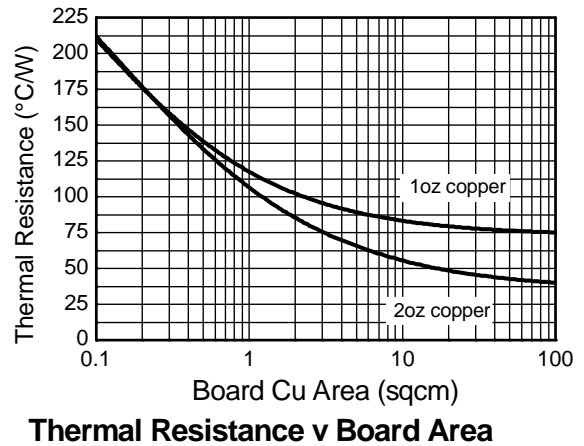
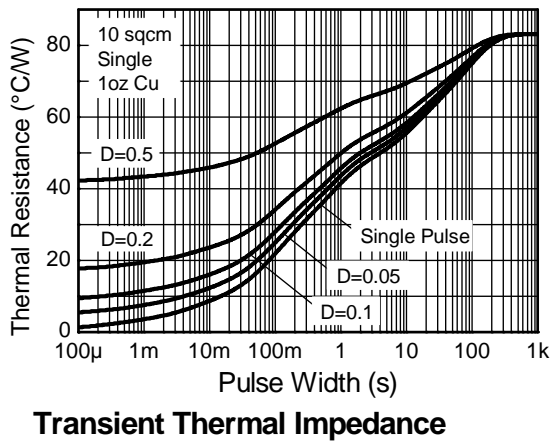
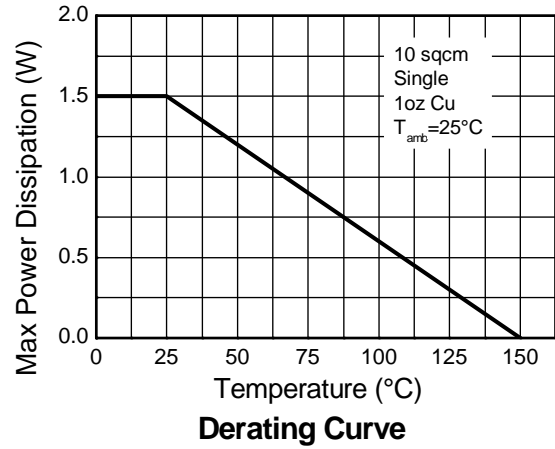
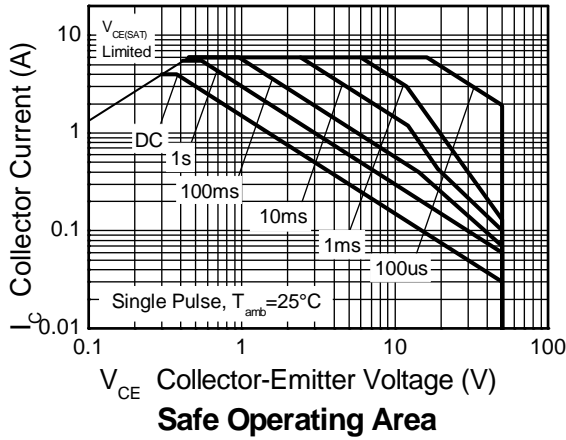
Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V <sub>CB0</sub>	100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	50	
Emitter-Base Voltage	V <sub>EBO</sub>	7	
Peak Pulse Current	I <sub>CM</sub>	6	A
Continuous Collector Current	(Note 3)	4	
	(Note 4)	4.3	
Base Current	I <sub>B</sub>	1	

**Thermal Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	1.5	W
		12	
Linear Derating Factor		2.45	
		19.6	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	83	°C/W
		51	
Thermal Resistance, Junction to Lead	R <sub>θJL</sub>	16.8	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

- Notes:
3. For a device surface mounted on 31mm x 31mm (10cm<sup>2</sup>) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.
  4. Same as note (3), except the device is measured at t ≤ 5 sec.
  5. For a single device, thermal resistance from junction to solder-point (at the end of the drain lead).

**Thermal Characteristics**

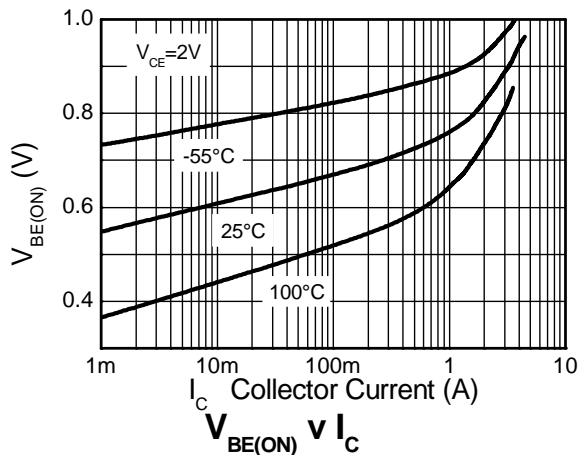
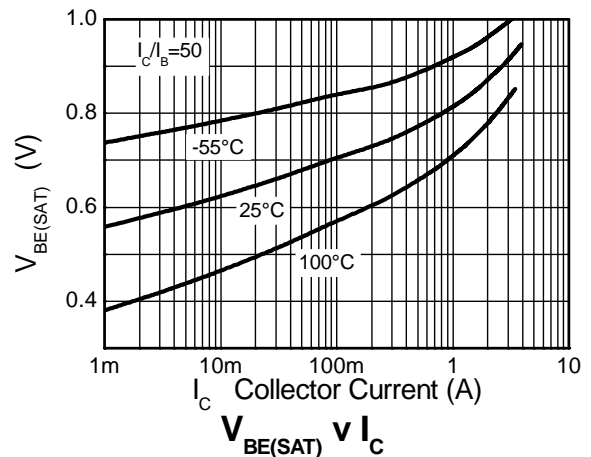
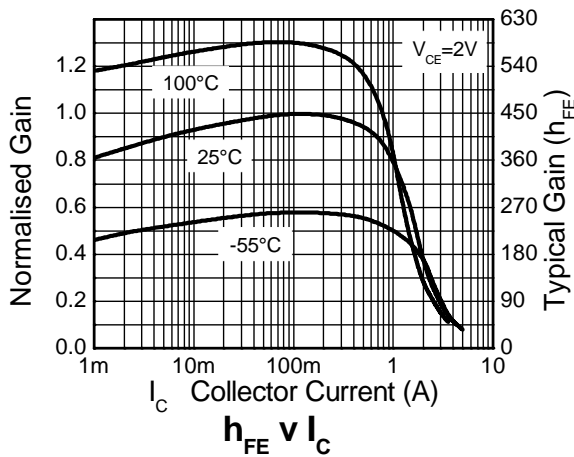
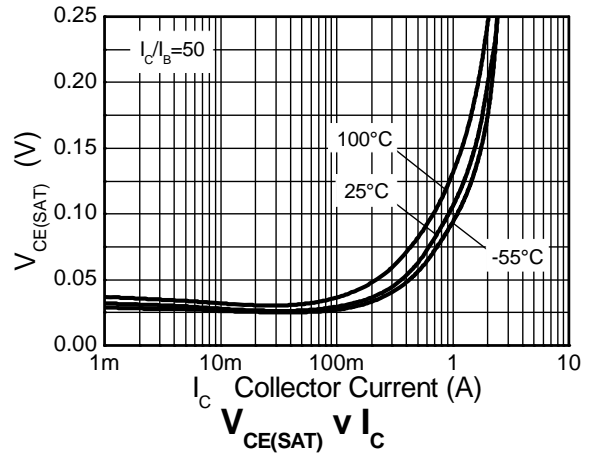
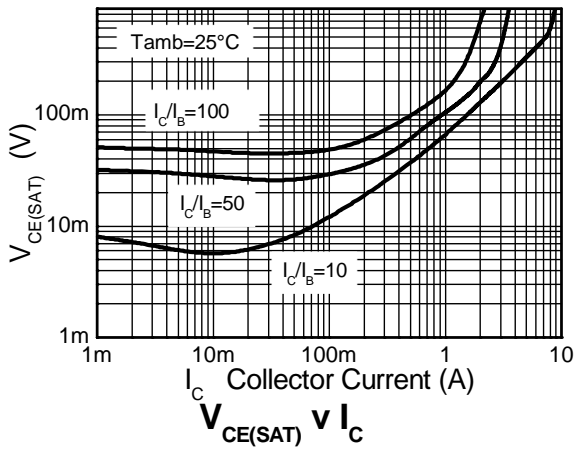


**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

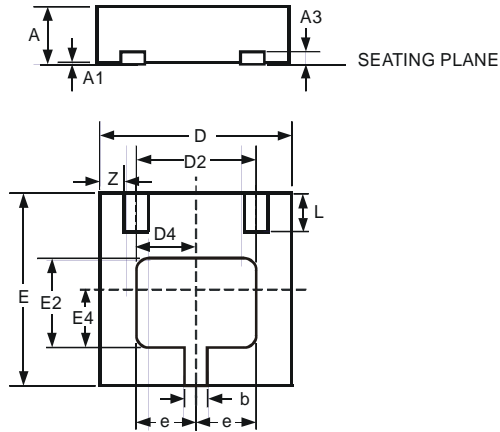
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	100	190	-	V	I <sub>C</sub> = 100 μA
Collector-Emitter Breakdown Voltage (Note 6)	BV <sub>CEO</sub>	50	65	-	V	I <sub>C</sub> = 10 mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.2	-	V	I <sub>E</sub> = 100 μA
Collector Cutoff Current	I <sub>CBO</sub>	-	-	100	nA	V <sub>CB</sub> = 80V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	100	nA	V <sub>EB</sub> = 6V
Collector Emitter Cutoff Current	I <sub>CES</sub>	-	-	100	nA	V <sub>CES</sub> = 40V
Static Forward Current Transfer Ratio (Note 6)	h <sub>FE</sub>	200	400	-	-	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 2V
		300	450	-		I <sub>C</sub> = 200mA, V <sub>CE</sub> = 2V
		200	400	-		I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V
		100	225	-		I <sub>C</sub> = 2A, V <sub>CE</sub> = 2V
		-	40	-		I <sub>C</sub> = 6A, V <sub>CE</sub> = 2V
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(sat)</sub>	-	10	20	mV	I <sub>C</sub> = 0.1A, I <sub>B</sub> = 10mA
		-	70	100		I <sub>C</sub> = 1A, I <sub>B</sub> = 5mA
		-	145	200		I <sub>C</sub> = 1A, I <sub>B</sub> = 10mA
		-	115	220		I <sub>C</sub> = 2A, I <sub>B</sub> = 50mA
		-	225	300		I <sub>C</sub> = 3A, I <sub>B</sub> = 100mA
		-	270	320		I <sub>C</sub> = 4A, I <sub>B</sub> = 200mA
Base-Emitter Turn-On Voltage (Note 6)	V <sub>BE(on)</sub>	-	0.94	1.00	V	I <sub>C</sub> = 4A, V <sub>CE</sub> = 2V
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(sat)</sub>	-	1.00	1.07	V	I <sub>C</sub> = 4A, I <sub>B</sub> = 200mA
Output Capacitance	C <sub>obo</sub>	-	12	20	pF	V <sub>CB</sub> = 10V, f = 1MHz
Transition Frequency	f <sub>T</sub>	100	165	-	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA, f = 100MHz
Turn-On Time	t <sub>on</sub>	-	170	-	ns	V <sub>CC</sub> = 10V, I <sub>C</sub> = 1A
Turn-Off Time	t <sub>off</sub>	-	750	-	ns	I <sub>B1</sub> = I <sub>B2</sub> = 10mA

Notes: 6. Measured under pulsed conditions. Pulse width ≤ 300 μs. Duty cycle ≤ 2%.

**Typical Electrical Characteristics**

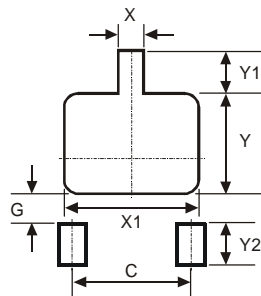


**Package Outline Dimensions**



DFN2020B-3			
Dim	Min	Max	Typ
A	0.57	0.63	0.60
A1	0	0.05	0.02
A3	—	—	0.152
b	0.20	0.30	0.25
D	1.95	2.075	2.00
D2	1.22	1.42	1.32
D4	0.56	0.76	0.66
e	—	—	0.65
E	1.95	2.075	2.00
E2	0.79	0.99	0.89
E4	0.48	0.68	0.58
L	0.25	0.35	0.30
Z	—	—	0.225
All Dimensions in mm			

**Suggested Pad Layout**



Dimensions	Value (in mm)
C	1.30
G	0.24
X	0.35
X1	1.52
Y	1.09
Y1	0.47
Y2	0.50

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